-100V P-CHANNEL ENHANCEMENT MODE MOSFET

MAIN CHARACTERISTICS

I_D	
V_{DSS}	
R_{DSON}-typ(@V_{GS}=-10V)	(Typ:80mΩ)

APPLICATIONS

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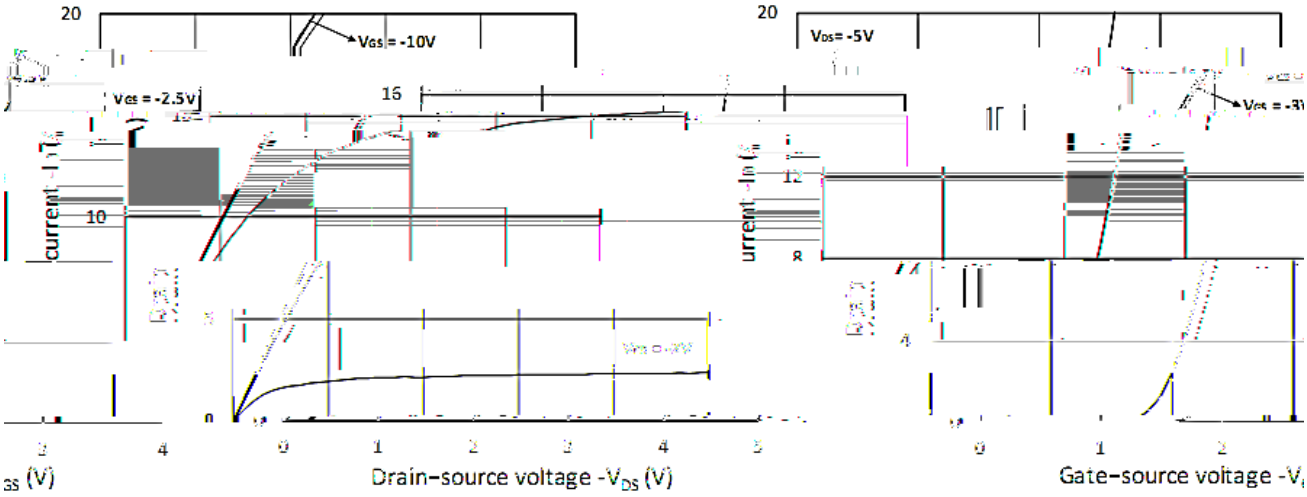
Maximum Ratings at Tc=25°C unless otherwise specified

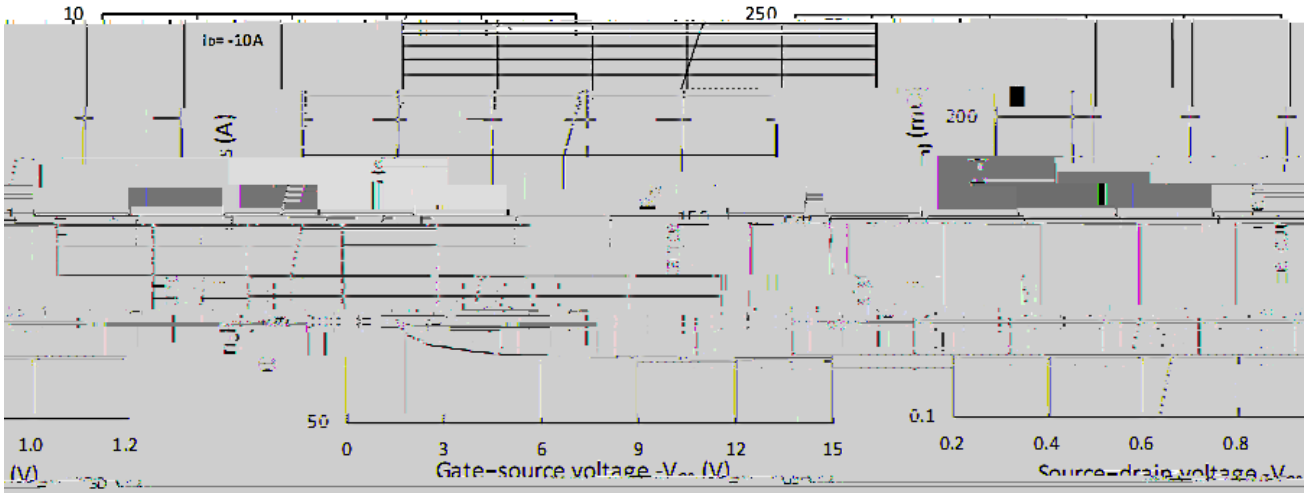
Characteristics	Symbols	Value t

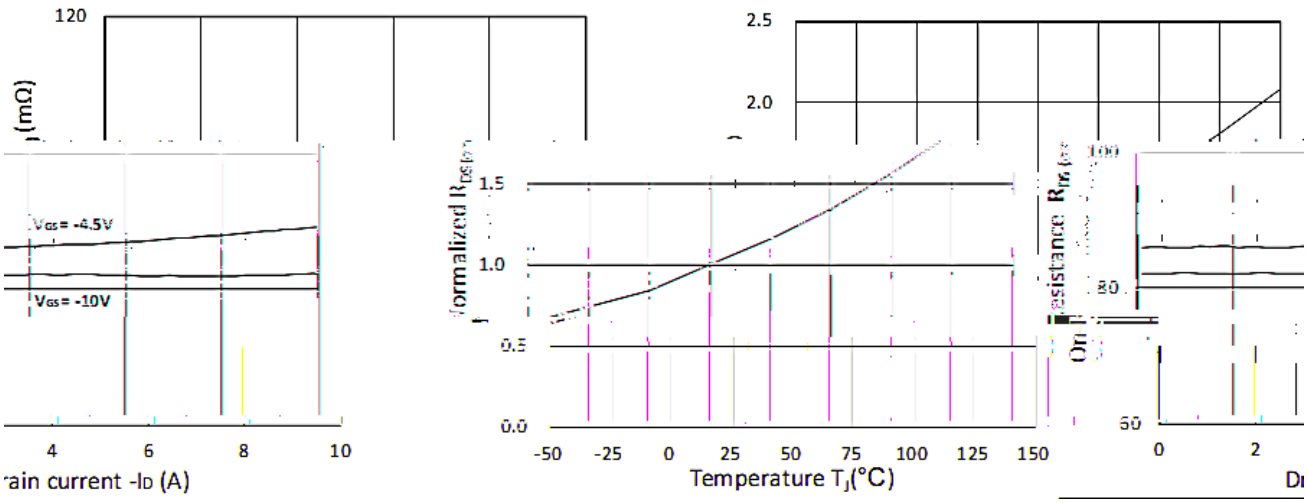
Electrical Characteristics (T_J=25 , unless otherwise noted)

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
		BV_{DSS}				V
		I_{GSS}				nA
		I_{DSS}				μA
						μA
		$V_{GS(th)}$				V
		$R_{DS(ON)}$				mΩ
						S
		C_{iss}				
		C_{oss}				pF
		C_{rss}				
						Ω
		Q_g				nC
		Q_{gs}				

Typical Characteristics







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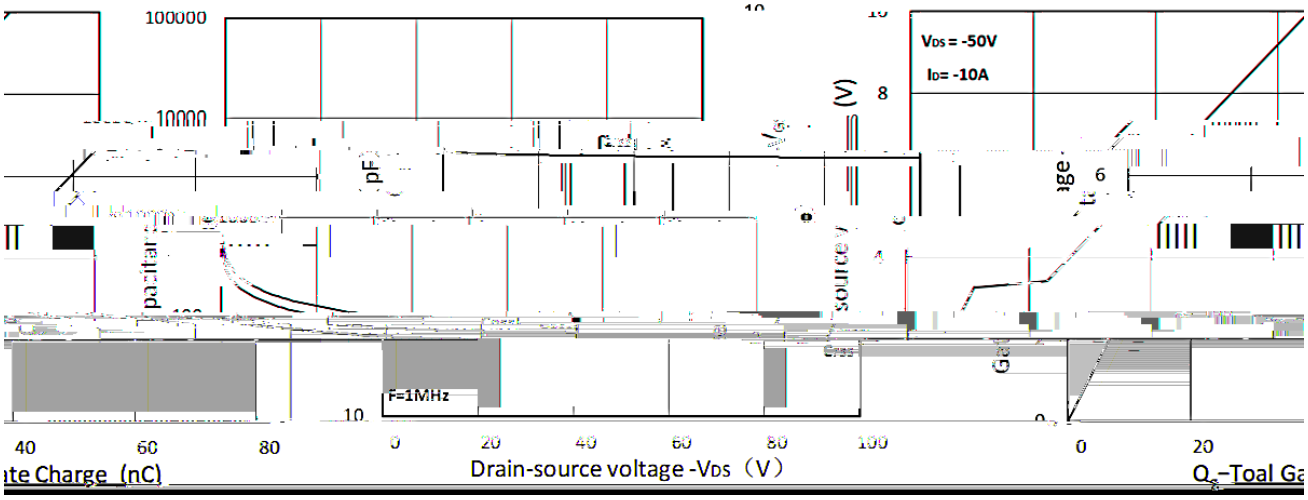

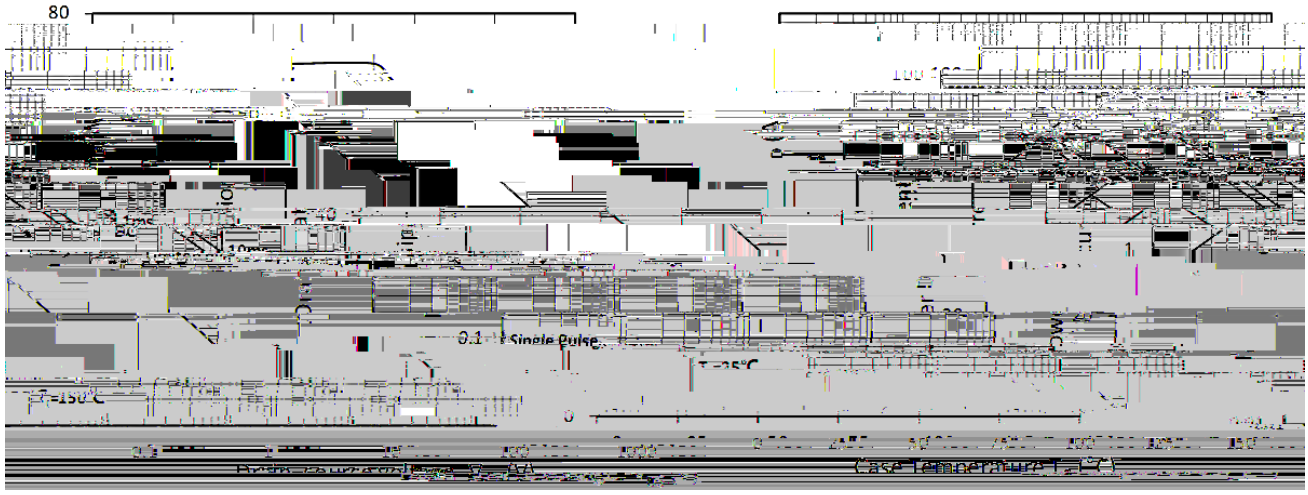

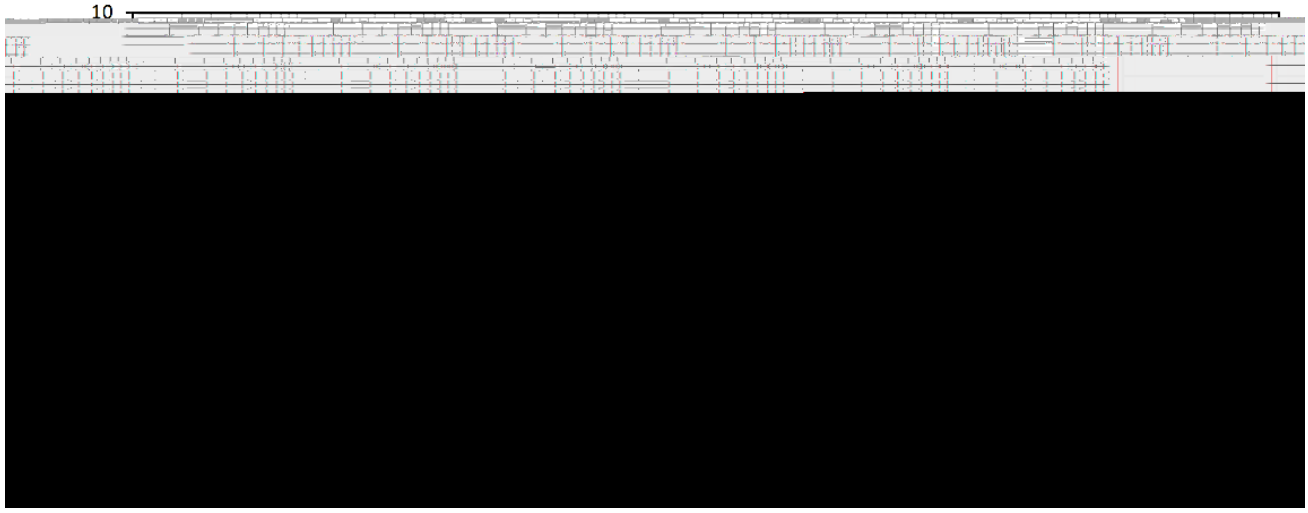

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